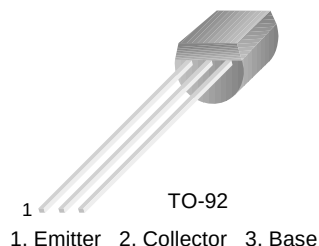


# KSR2007

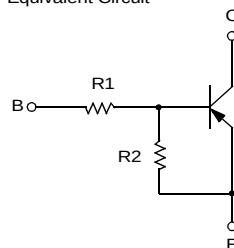
KSR2007

## Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ( $R_1=22K\Omega$ ,  $R_2=47K\Omega$ )
- Complement to KSR1007



Equivalent Circuit



## PNP Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                 | Value     | Units            |
|-----------|---------------------------|-----------|------------------|
| $V_{CBO}$ | Collector-Base Voltage    | -50       | V                |
| $V_{CEO}$ | Collector-Emitter Voltage | -50       | V                |
| $V_{EBO}$ | Emitter-Base Voltage      | -10       | V                |
| $I_C$     | Collector Current         | -100      | mA               |
| $P_C$     | Collector Dissipation     | 300       | mW               |
| $T_J$     | Junction Temperature      | 150       | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature       | -55 ~ 150 | $^\circ\text{C}$ |

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol            | Parameter                            | Test Condition                                          | Min. | Typ. | Max. | Units         |
|-------------------|--------------------------------------|---------------------------------------------------------|------|------|------|---------------|
| $BV_{CBO}$        | Collector-Base Breakdown Voltage     | $I_C = -10\mu\text{A}$ , $I_E = 0$                      | -50  |      |      | V             |
| $BV_{CEO}$        | Collector-Emitter Breakdown Voltage  | $I_C = -100\mu\text{A}$ , $I_B = 0$                     | -50  |      |      | V             |
| $I_{CBO}$         | Collector Cut-off Current            | $V_{CB} = -40\text{V}$ , $I_E = 0$                      |      |      | -0.1 | $\mu\text{A}$ |
| $h_{FE}$          | DC Current Gain                      | $V_{CE} = -5\text{V}$ , $I_C = -5\text{mA}$             | 68   |      |      |               |
| $V_{CE(sat)}$     | Collector-Emitter Saturation Voltage | $I_C = -10\text{mA}$ , $I_B = -0.5\text{mA}$            |      |      | -0.3 | V             |
| $C_{ob}$          | Output Capacitance                   | $V_{CB} = -10\text{V}$ , $I_E = 0$<br>$f = 1\text{MHz}$ |      | 5.5  |      | pF            |
| $f_T$             | Current Gain-Bandwidth Product       | $V_{CE} = -10\text{V}$ , $I_C = -5\text{mA}$            |      | 200  |      | MHz           |
| $V_I(\text{off})$ | Input Off Voltage                    | $V_{CE} = -5\text{V}$ , $I_C = -100\mu\text{A}$         | -0.4 |      |      | V             |
| $V_I(\text{on})$  | Input On Voltage                     | $V_{CE} = -0.3\text{V}$ , $I_C = -2\text{mA}$           |      |      | -2.5 | V             |
| $R_1$             | Input Resistor                       |                                                         | 15   | 22   | 29   | $K\Omega$     |
| $R_1/R_2$         | Resistor Ratio                       |                                                         | 0.42 | 0.47 | 0.52 |               |

## Typical Characteristics

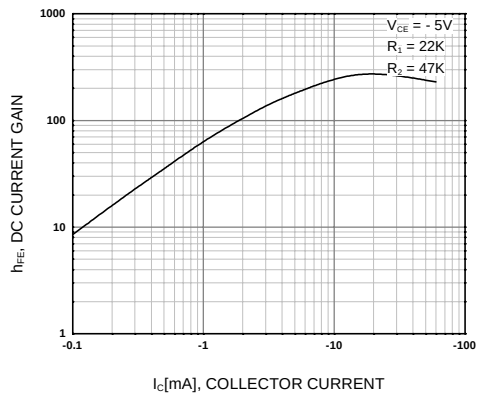


Figure 1. DC current Gain

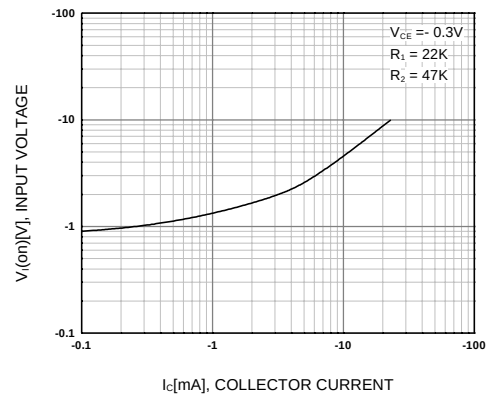


Figure 2. Input On Voltage

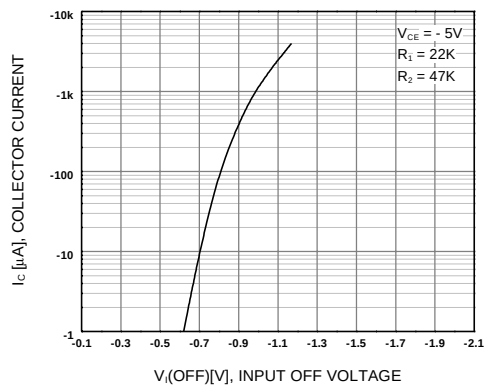


Figure 3. Input Off Voltage

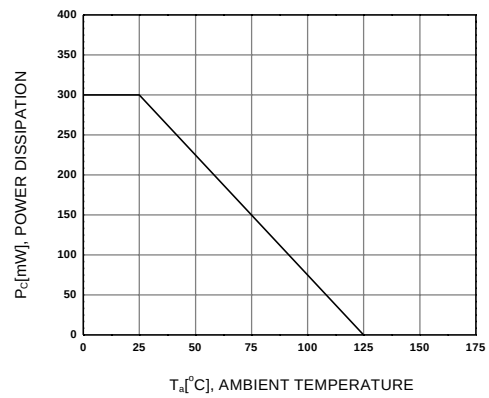
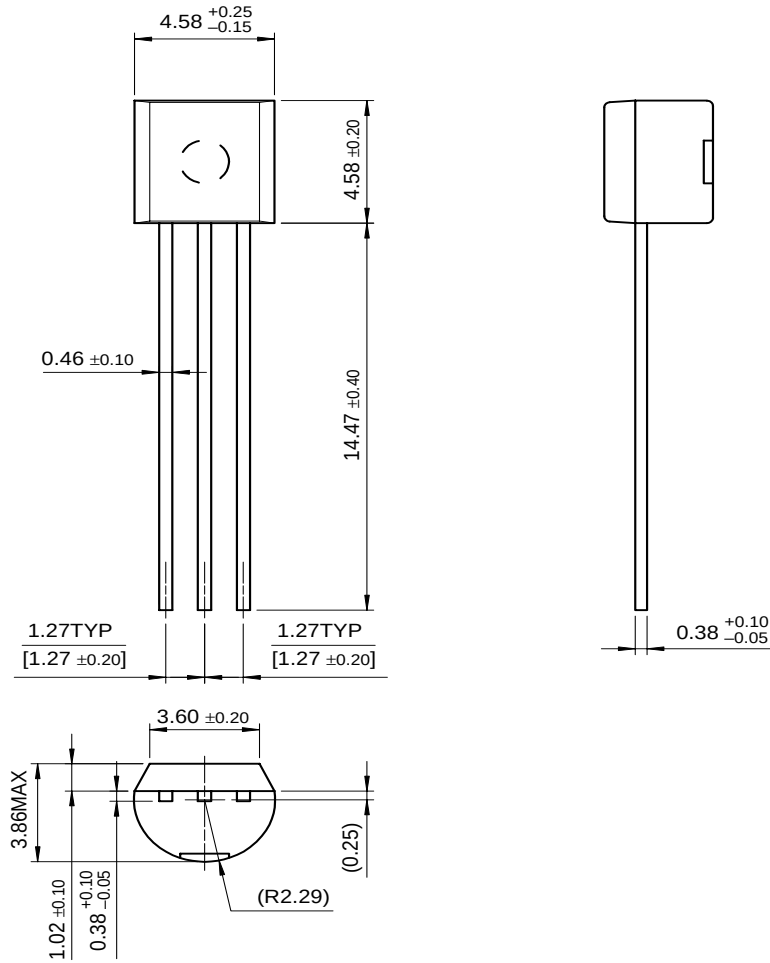


Figure 4. Power Derating

# Package Dimensions

## TO-92



Dimensions in Millimeters

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| CoolFET™             | GTO™                | QS™                 | VCX™       |
| CROSSVOLT™           | HiSeC™              | QT Optoelectronics™ | UHC™       |
| DOME™                | ISOPLANAR™          | Quiet Series™       |            |
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